

V_{DSS}	1200V
$R_{DS(on)}$ (Typ.)	80m Ω
I_D	40A

●Outline

TO-247N



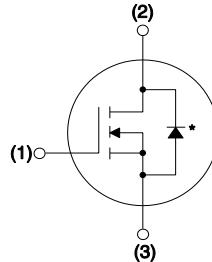
●Features

- 1) Low on-resistance
- 2) Fast switching speed
- 3) Fast reverse recovery
- 4) Easy to parallel
- 5) Simple to drive
- 6) Pb-free lead plating ; RoHS compliant

●Application

- Solar inverters
- DC/DC converters
- Induction heating
- Motor drives

●Inner circuit



(1) Gate
(2) Drain
(3) Source
* Body Diode

●Packaging specifications

Package	TO-247N
Type	Packing
	Reel size (mm)
	Tape width (mm)
	Basic ordering unit (pcs)
	Packing code
	Marking

●Absolute maximum ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Drain - Source voltage	V_{DSS}	1200	V
Continuous drain current	I_D ^{*1}	40	A
	I_D ^{*1}	28	A
Pulsed drain current	$I_{D,pulse}$ ^{*2}	80	A
Gate - Source voltage (DC)	V_{GSS}	-6 to +22	V
Gate - Source surge voltage ($t_{surge} < 300\text{nsec}$)	$V_{GSS,surge}$ ^{*3}	-10 to +26	V
Total power dissipation	$T_C=25^\circ\text{C}$, See Fig.1	262	W
	$T_C=100^\circ\text{C}$, See Fig.1	130	W
Junction temperature	T_j	175	°C
Range of storage temperature	T_{stg}	-55 to +175	°C

●Electrical characteristics ($T_a = 25^\circ\text{C}$)

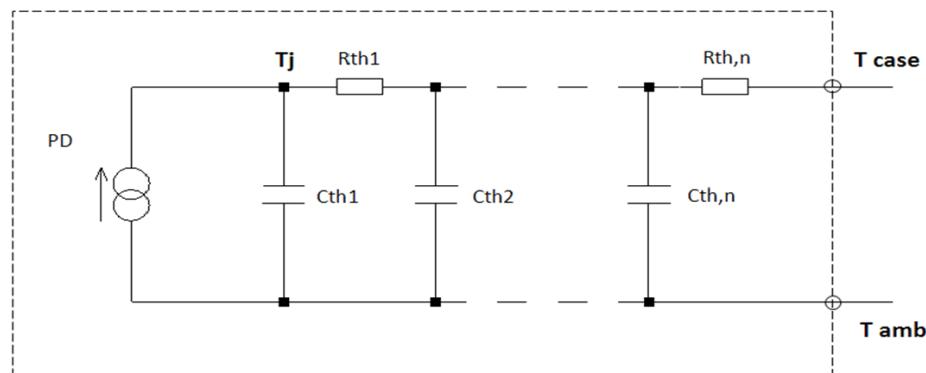
Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Drain - Source breakdown voltage	$V_{(\text{BR})\text{DSS}}$	$V_{\text{GS}} = 0\text{V}, I_D = 1\text{mA}$	1200	-	-	V
Zero gate voltage drain current	I_{DSS}	$V_{\text{DS}} = 1200\text{V}, V_{\text{GS}} = 0\text{V}$	-	1	10	μA
		$T_j = 25^\circ\text{C}$	-	2	-	
Gate - Source leakage current	$I_{\text{GSS+}}$	$V_{\text{GS}} = +22\text{V}, V_{\text{DS}} = 0\text{V}$	-	-	100	nA
Gate - Source leakage current	$I_{\text{GSS-}}$	$V_{\text{GS}} = -6\text{V}, V_{\text{DS}} = 0\text{V}$	-	-	-100	nA
Gate threshold voltage	$V_{\text{GS (th)}}$	$V_{\text{DS}} = V_{\text{GS}}, I_D = 4.4\text{mA}$	1.6	2.8	4.0	V

●Thermal resistance

Parameter	Symbol	Values			Unit
		Min.	Typ.	Max.	
Thermal resistance, junction - case	R_{thJC}	-	0.44	0.57	°C/W

●Typical Transient Thermal Characteristics

Symbol	Value	Unit	Symbol	Value	Unit
R_{th1}	7.80E-02	K/W	C_{th1}	5.00E-03	Ws/K
R_{th2}	1.97E-01		C_{th2}	1.80E-02	
R_{th3}	1.62E-01		C_{th3}	2.49E-01	



●Electrical characteristics ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Static drain - source on - state resistance	$R_{DS(on)}^{*4}$	$V_{GS} = 18\text{V}$, $I_D = 10\text{A}$ $T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	-	80	117	$\text{m}\Omega$
Gate input resistance	R_G	$f = 1\text{MHz}$, open drain	-	6.3	-	Ω
Transconductance	g_{fs}^{*4}	$V_{DS} = 10\text{V}$, $I_D = 10\text{A}$	-	3.7	-	S
Input capacitance	C_{iss}	$V_{GS} = 0\text{V}$	-	2080	-	pF
Output capacitance	C_{oss}	$V_{DS} = 800\text{V}$	-	77	-	
Reverse transfer capacitance	C_{rss}	$f = 1\text{MHz}$	-	16	-	
Effective output capacitance, energy related	$C_{o(er)}$	$V_{GS} = 0\text{V}$ $V_{DS} = 0\text{V to } 500\text{V}$	-	116	-	pF
Turn - on delay time	$t_{d(on)}^{*4}$	$V_{DD} = 400\text{V}$, $V_{GS} = 18\text{V}$	-	35	-	ns
Rise time	t_r^{*4}	$I_D = 10\text{A}$	-	36	-	
Turn - off delay time	$t_{d(off)}^{*4}$	$R_L = 40\Omega$	-	76	-	
Fall time	t_f^{*4}	$R_G = 0\Omega$	-	22	-	
Turn - on switching loss	E_{on}^{*4}	$V_{DD} = 600\text{V}$, $I_D = 10\text{A}$ $V_{GS} = 18\text{V}/0\text{V}$ $R_G = 0\Omega$, $L = 500\mu\text{H}$	-	174	-	μJ
Turn - off switching loss	E_{off}^{*4}	* E_{on} includes diode reverse recovery	-	51	-	

●Gate Charge characteristics ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Total gate charge	Q_g^{*4}	$V_{DD} = 400\text{V}$ $I_D = 10\text{A}$	-	106	-	nC
Gate - Source charge	Q_{gs}^{*4}		-	27	-	
Gate - Drain charge	Q_{gd}^{*4}		-	31	-	
Gate plateau voltage	$V_{(plateau)}$	$V_{DD} = 400\text{V}$, $I_D = 10\text{A}$	-	9.7	-	V

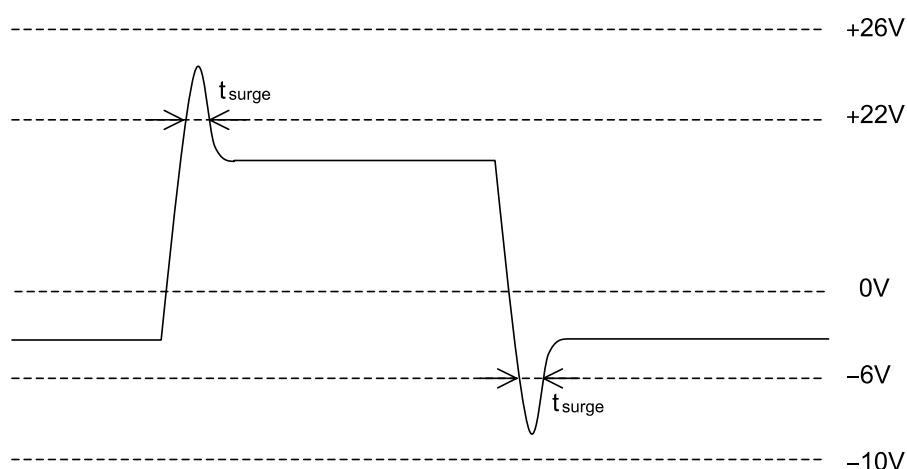
●Body diode electrical characteristics (Source-Drain) ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Body diode continuous, forward current	I_S^{*1}		-	-	40	A
Body diode direct current, pulsed	I_{SM}^{*2}	$T_c = 25^\circ\text{C}$	-	-	80	A
Forward voltage	V_{SD}^{*4}	$V_{GS} = 0\text{V}, I_S = 10\text{A}$	-	4.6	-	V
Reverse recovery time	t_{rr}^{*4}	$I_F = 10\text{A}, V_R = 400\text{V}$ $di/dt = 150\text{A}/\mu\text{s}$	-	31	-	ns
Reverse recovery charge	Q_{rr}^{*4}		-	44	-	nC
Peak reverse recovery current	I_{rrm}^{*4}		-	2.3	-	A

*1 Limited only by maximum temperature allowed.

*2 PW $\leq 10\mu\text{s}$, Duty cycle $\leq 1\%$

*3 Example of acceptable V_{GS} waveform



*4 Pulsed

●Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

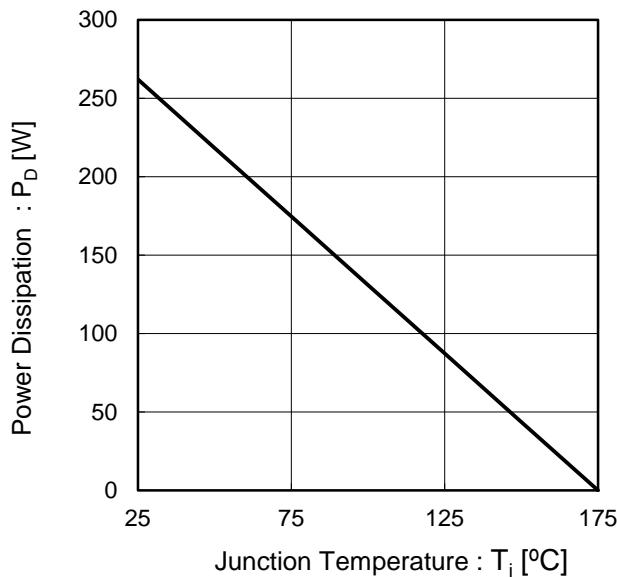


Fig.2 Maximum Safe Operating Area

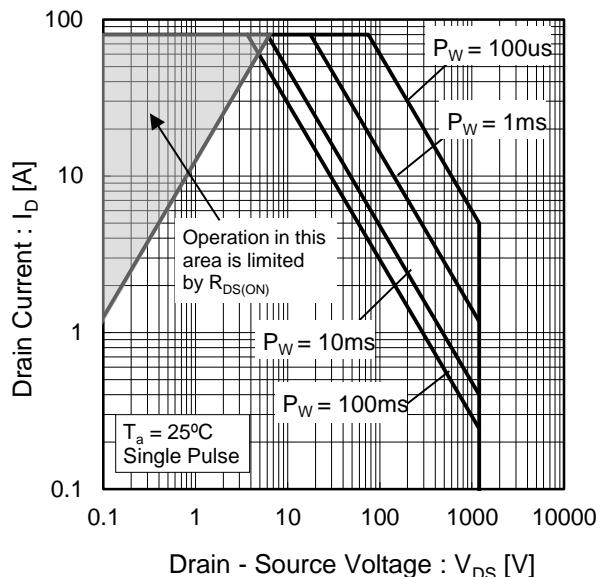
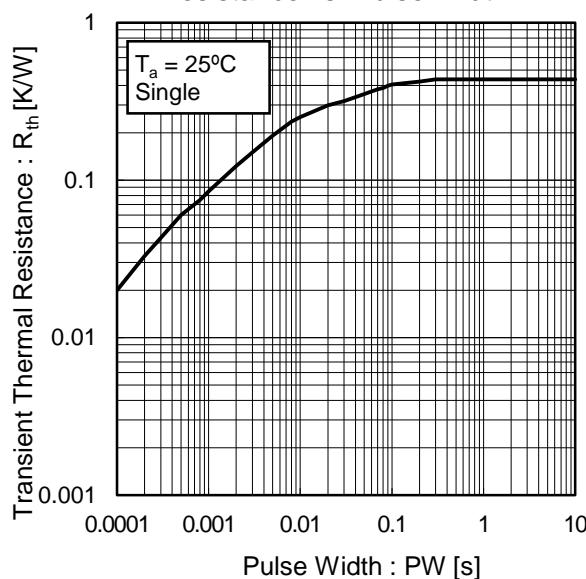


Fig.3 Typical Transient Thermal Resistance vs. Pulse Width



●Electrical characteristic curves

Fig.4 Typical Output Characteristics(I)

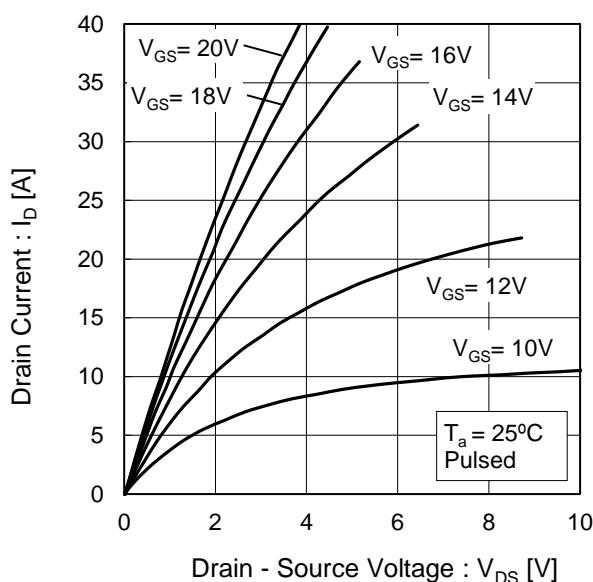


Fig.5 Typical Output Characteristics(II)

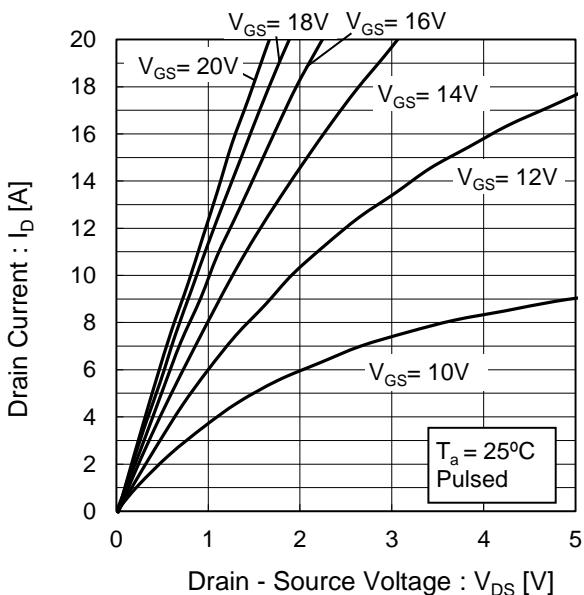


Fig.6 Typical Output Characteristics(I)

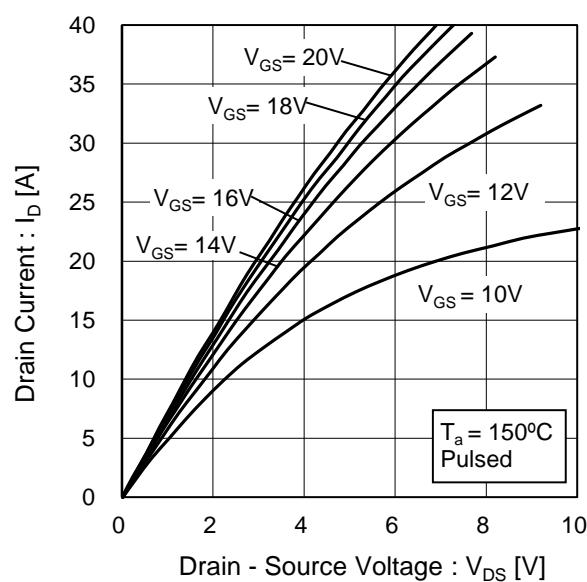
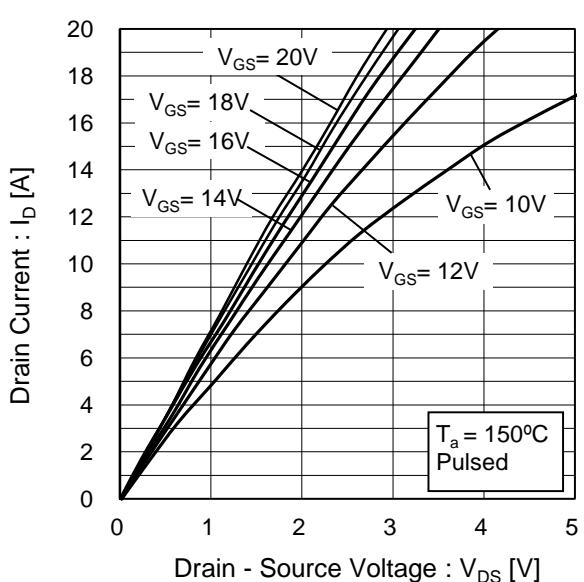


Fig.7 Typical Output Characteristics(II)



●Electrical characteristic curves

Fig.8 Typical Transfer Characteristics

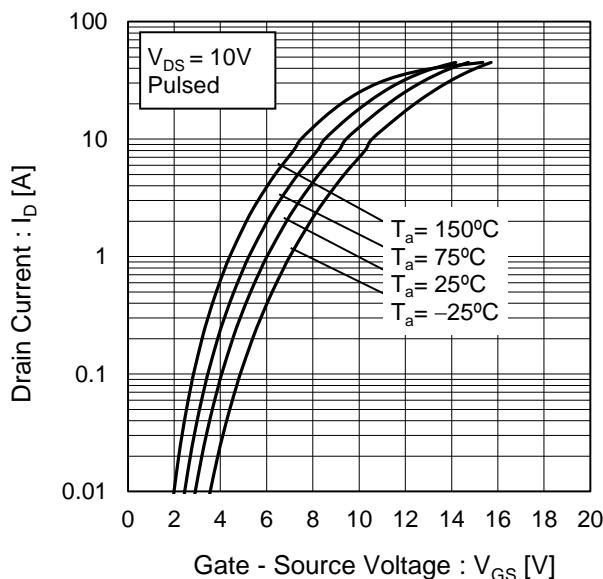


Fig.9 Typical Transfer Characteristics (II)

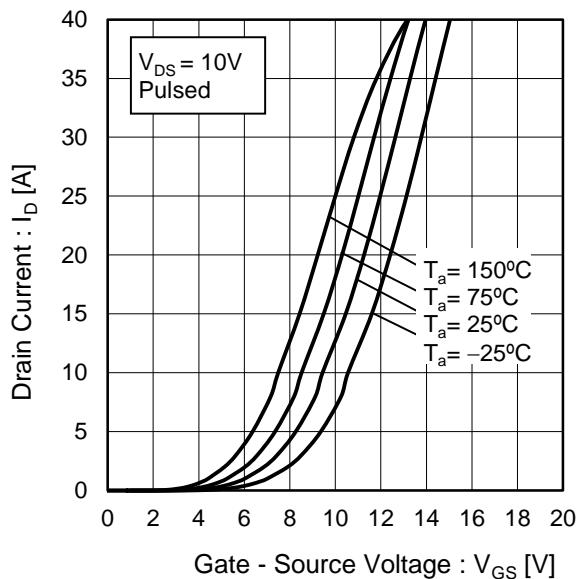


Fig.10 Gate Threshold Voltage vs. Junction Temperature

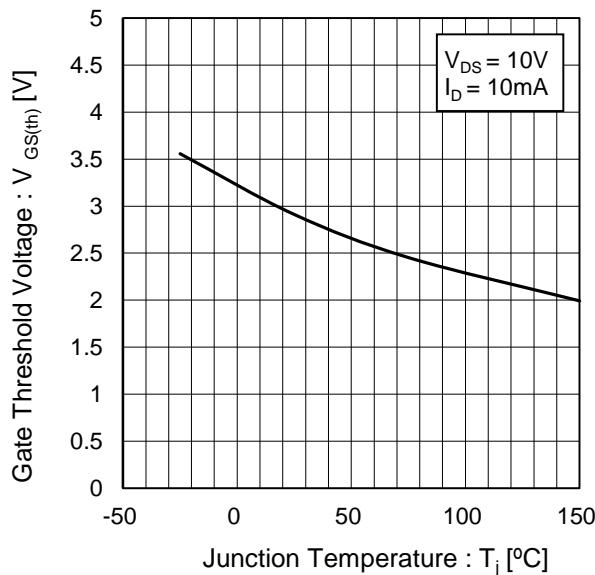
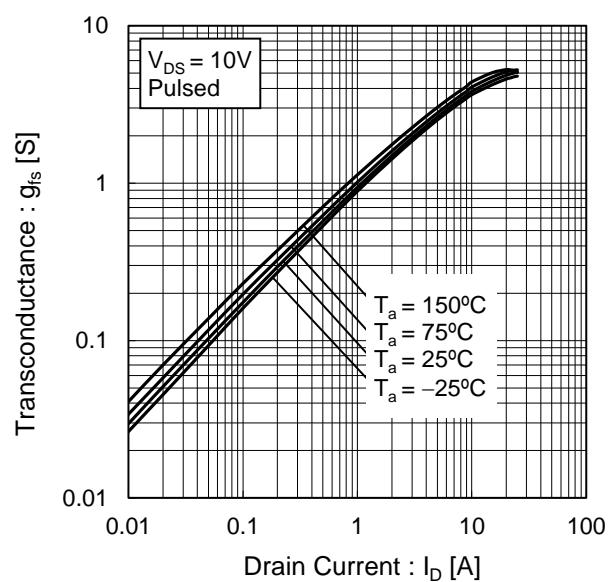


Fig.11 Transconductance vs. Drain Current



●Electrical characteristic curves

Fig.12 Static Drain - Source On - State
Resistance vs. Gate - Source Voltage

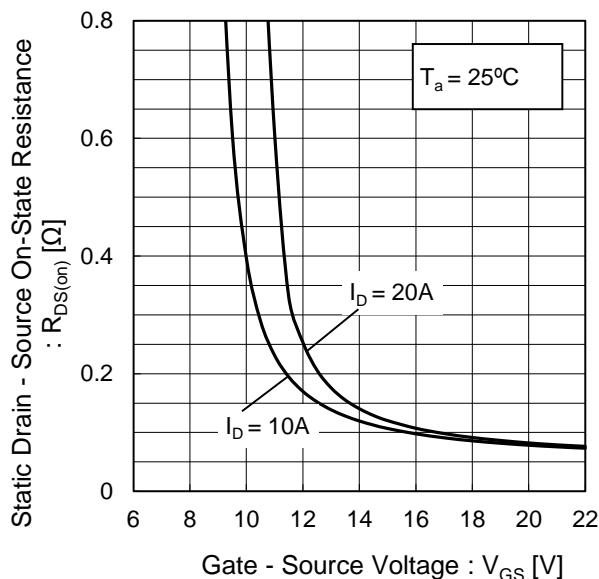


Fig.13 Static Drain - Source On - State
Resistance vs. Junction Temperature

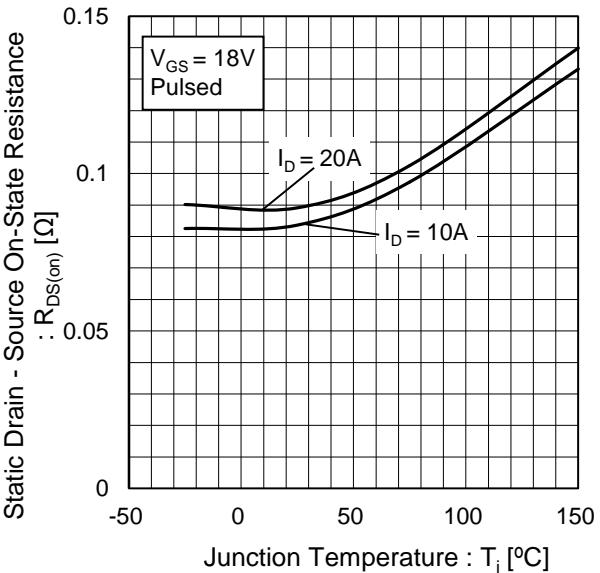
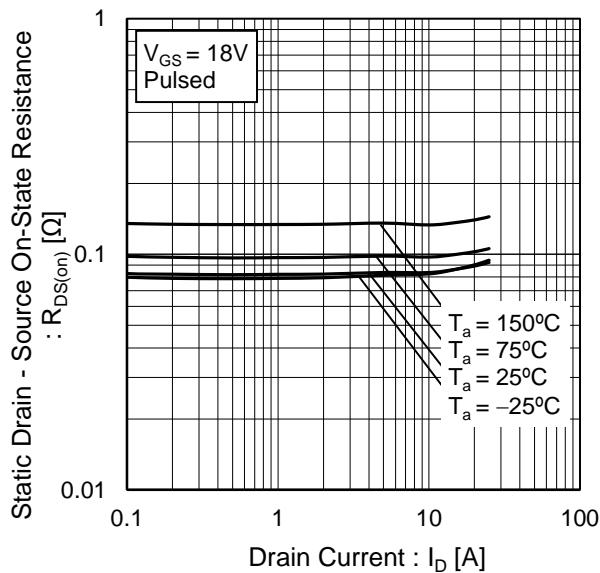


Fig.14 Static Drain - Source On - State
Resistance vs. Drain Current



●Electrical characteristic curves

Fig.15 Typical Capacitance vs. Drain - Source Voltage

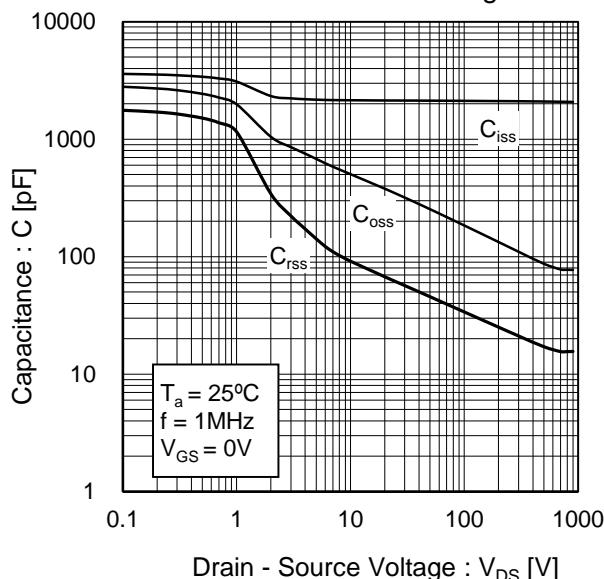


Fig.16 C_{oss} Stored Energy

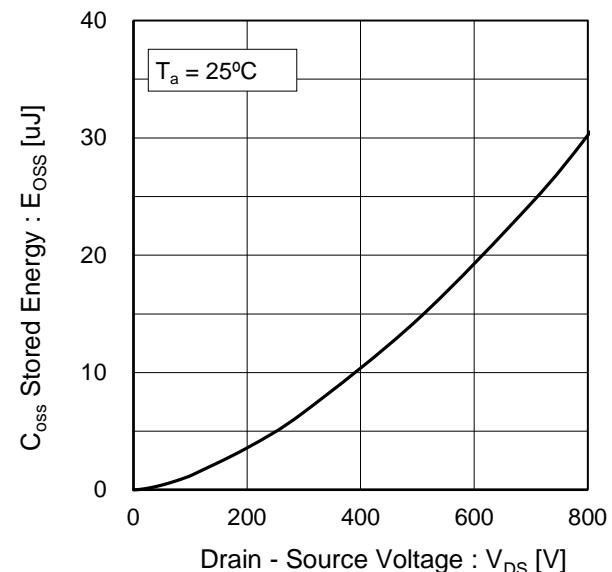


Fig.17 Switching Characteristics

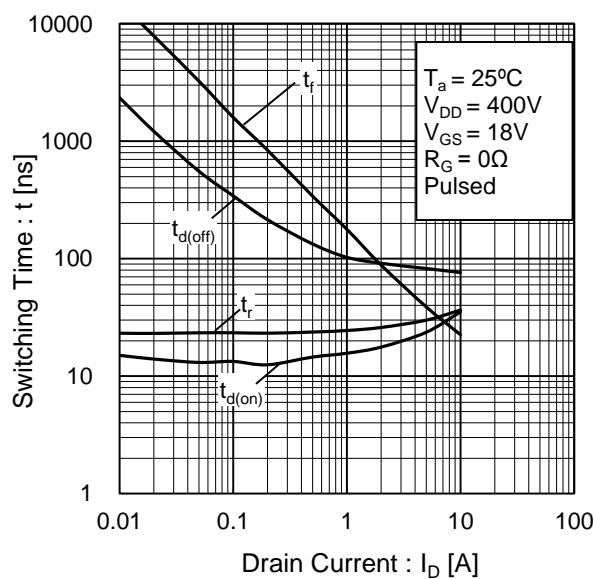
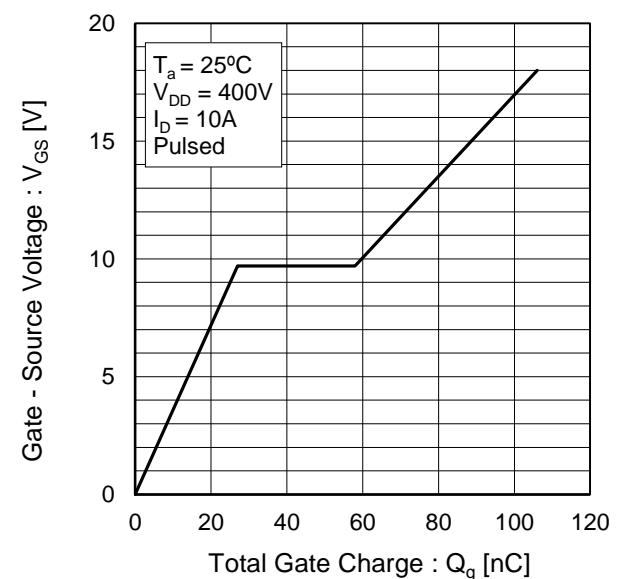


Fig.18 Dynamic Input Characteristics



●Electrical characteristic curves

Fig.19 Typical Switching Loss
vs. Drain - Source Voltage

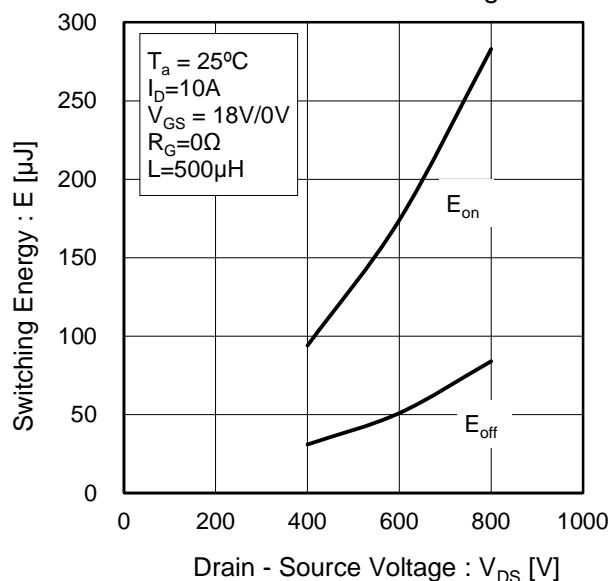


Fig.20 Typical Switching Loss
vs. Drain Current

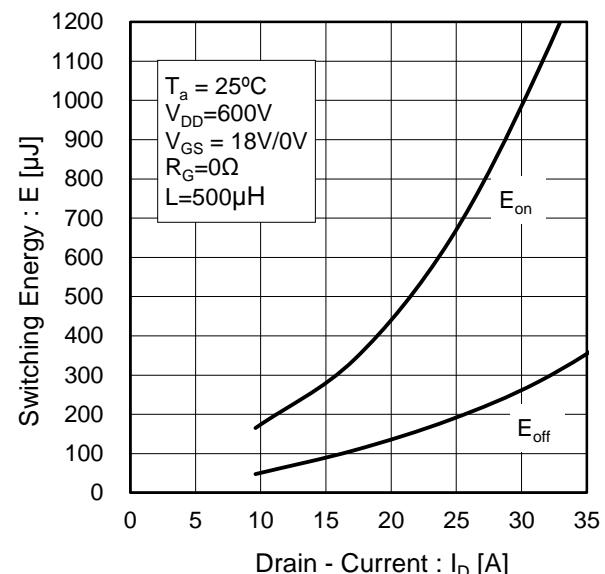
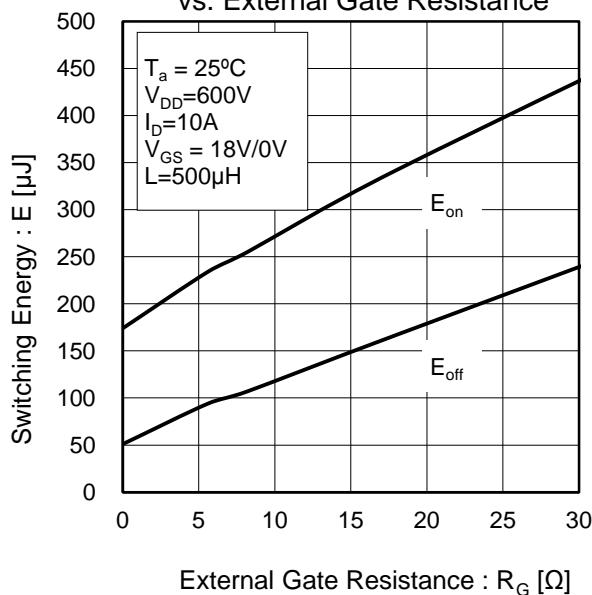


Fig.21 Typical Switching Loss
vs. External Gate Resistance



●Electrical characteristic curves

Fig.22 Body Diode Forward Current vs. Source - Drain Voltage

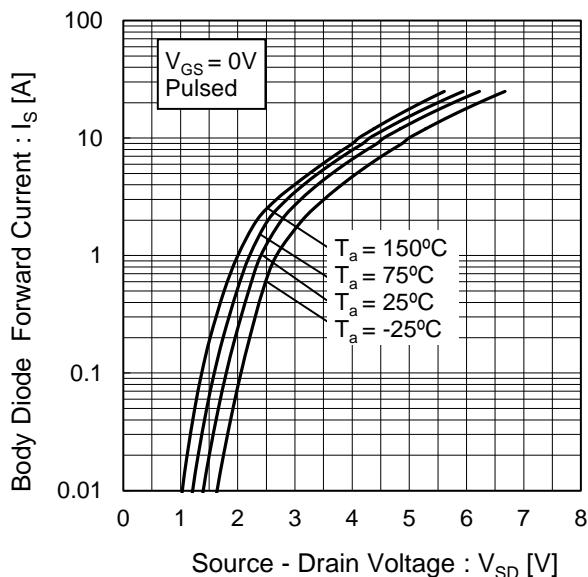
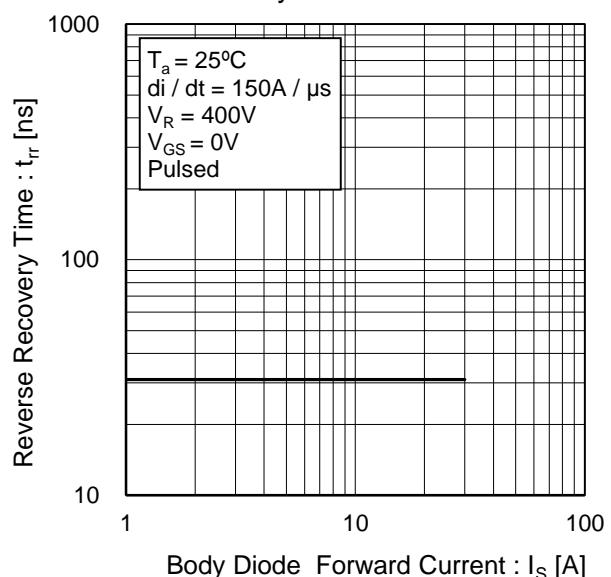


Fig.23 Reverse Recovery Time vs. Body Diode Forward Current



●Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

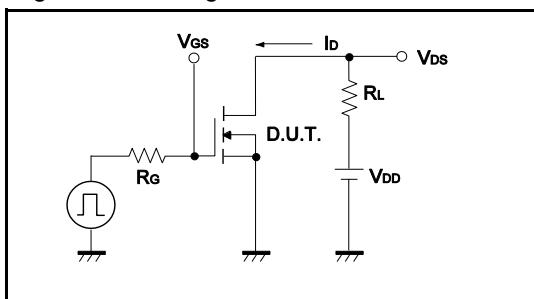


Fig.1-2 Switching Waveforms

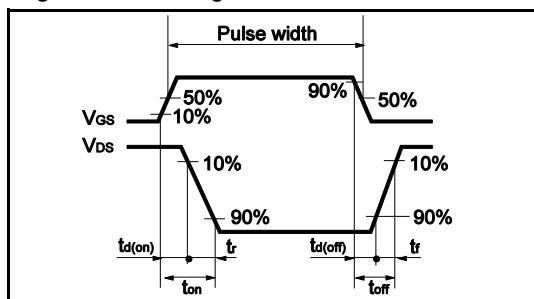


Fig.2-1 Gate Charge Measurement Circuit

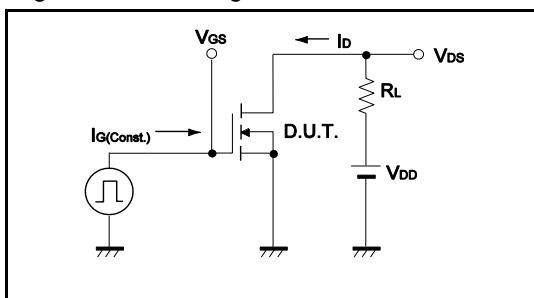


Fig.2-2 Gate Charge Waveform

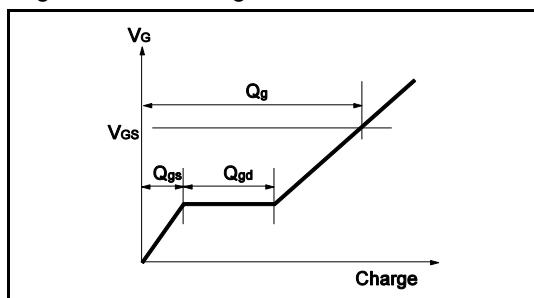


Fig.3-1 Switching Energy Measurement Circuit

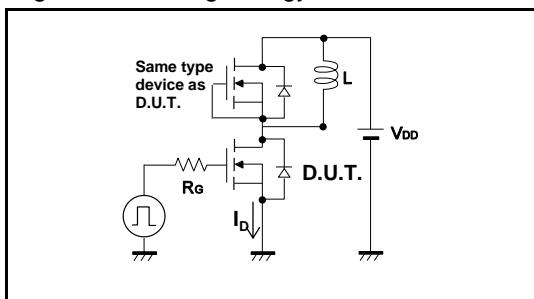


Fig.3-2 Switching Waveforms

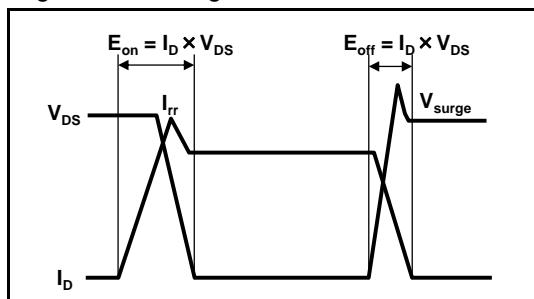


Fig.4-1 Reverse Recovery Time Measurement Circuit

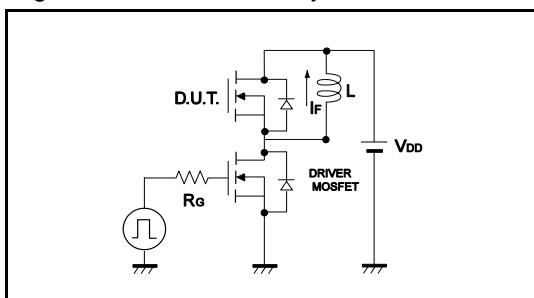
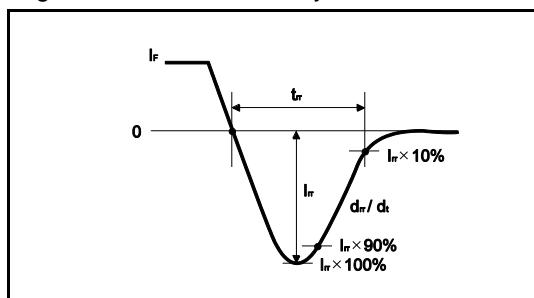


Fig.4-2 Reverse Recovery Waveform



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